

Features

- Split Gate Trench MOSFET Technology
- **Excellent Stability and Uniformity**
- Moisture Sensitivity Level 1
- Halogen Free. "Green" Device(Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

• Operating Junction Temperature Range: -55°C to +150°C

• Storage Temperature Range: -55°C to +150°C

• Thermal Resistance: 40°C/W Junction to Ambient (Note 2)

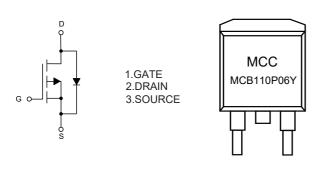
• Thermal Resistance: 1°C/W Junction to Case

Parameter		Symbol	Rating	Unit	
Drain -Source Voltage		V _{DS}	-60	V	
Gate -Source Volltage		V _{GS}	±20	V	
Drain Current-Continuous	T _C =25°C		-110	А	
	T _C =100°C	l _D	-69		
Drain Current-Pulse(Note 3)		I _{DM}	-440	Α	
Power Dissipation ^(Note 4)		P _D	125	W	
Single Pulsed Avalanche Energy ^(Note 5)		E _{AS}	625	mJ	

Note:

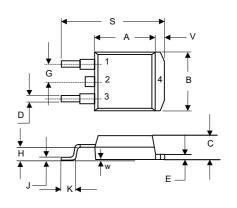
- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. The value of $R_{\rm BJA}$ is measured with the device mounted on $1 in^2$ FR-4 board with 2oz. Copper, in a still air environment with $T_{\rm A}$ =25°C.
- 3. Repetitive rating; pulse width limited by max. junction temperature.
- 4. P_D is based on max. junction temperature, using junction-case thermal resistance.
- 5. T_J =25°C, V_{DD} =-40V, V_{GS} =-10V, R_G =25Ω, L=2mH.

Internal Structure and Marking Code



P-CHANNEL **MOSFET**

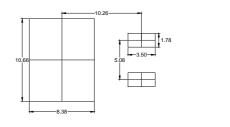
D²-PAK



DIMENSIONS					
DIM INCHES		MM		NOTE	
DIIVI	MIN	MAX	MIN	MAX	NOIL
Α	0.331	0.370	8.40	9.40	
В	0.378	0.417	9.60	10.60	
С	0.165	0.189	4.20	4.80	
D	0.027	0.037	0.68	0.94	
Е	0.045	0.055	1.14	1.40	
G	0.10		2.54		TYP.
Н	0.096	0.134	2.43	3.40	
J	0.011	0.025	0.28	0.64	
K	0.071	0.131	1.80	3.32	
S	0.575	0.625	14.60	15.87	
V	0.042	0.058	1.07	1.47	
W	0.000	0.010	0.00	0.25	

Suggested Solder Pad Layout

Unit:mm





Electrical Characteristics @ 25°C (Unless Otherwise Noted)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static Characteristics			,				
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =-250μA	-60			V	
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-60V, V _{GS} =0V			-1	μΑ	
Gate-Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250μA	-2.0	-2.6	-3.5	V	
Drain-Source On-Resistance		V _{GS} =-10V, I _D =-20A		6.2 8.4		0	
	$R_{DS(on)}$	V _{GS} =-6V, I _D =-20A	7.4		10	mΩ	
Gate Resistance	R _g	f=1MHz, Open drain		8		Ω	
Diode Characteristics			<u>'</u>	1			
Continuous Body Diode Current	Is				-110	Α	
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =-20A			-1.2	V	
Reverse Recovery Time	t _{rr}	I _s =-40A,di/dt=100A/μs		59		ns	
Reverse Recovery Charge	Q _{rr}	1 _S 40A,αι/αι-100A/μS		88		nC	
Dynamic Characteristics							
Input Capacitance	C _{iss}			5352			
Output Capacitance	C _{oss}	V_{DS} =-30V, V_{GS} =0V,f=1MHz		926		pF	
Reverse Transfer Capacitance	C _{rss}			44		1	
Total Gate Charge	Qg			83			
Gate-Source Charge	Q_{gs}	V_{DS} =-30V, V_{GS} =-10V, I_{D} =-3A		16		nC	
Gate-Drain Charge	Q_{gd}			18			
Turn-On Delay Time	t _{d(on)}			15			
Turn-On Rise Time	t _r	V _{DD} =-30V, V _{GS} =-10V,		26			
Turn-Off Delay Time	t _{d(off)}	$R_G=6\Omega$, $I_D=-3A$		200		ns	
Turn-Off Fall Time	t _f			83			



Curve Characteristics

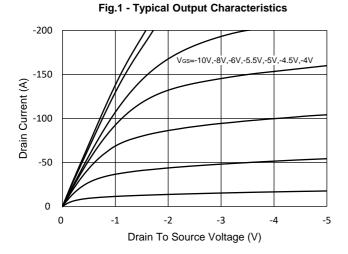


Fig.2 - Transfer Characteristic

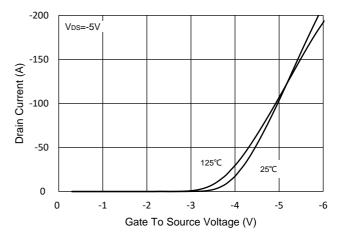


Fig.3 - R_{DS(ON)} - V_{GS}

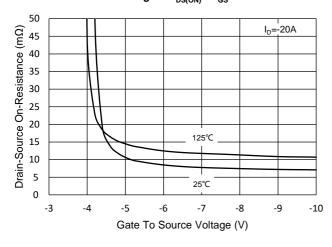


Fig.4 - R_{DS(ON)} - I_D

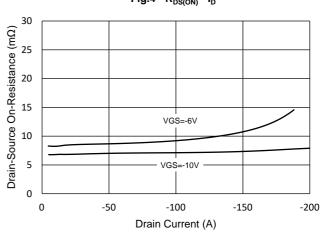


Fig.5 - Capacitance Characteristics

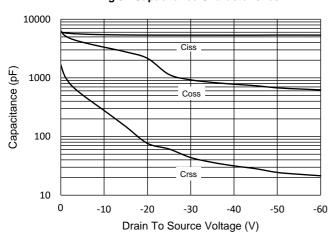
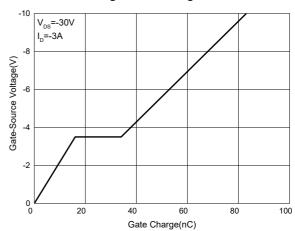
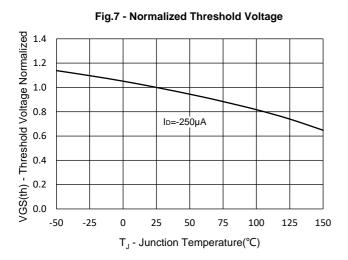


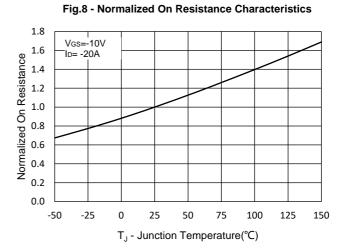
Fig.6 - Gate Charge

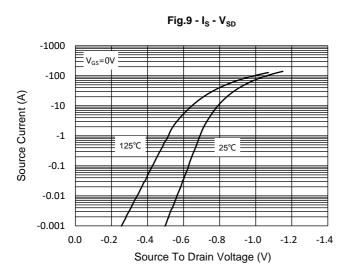


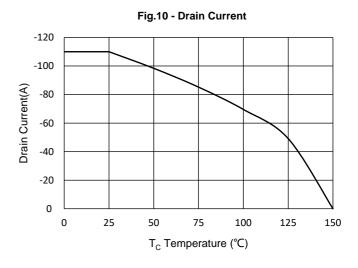


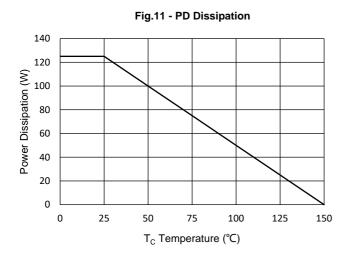
Curve Characteristics





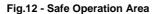








Curve Characteristics



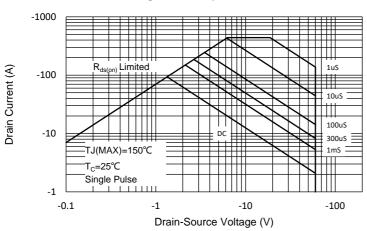
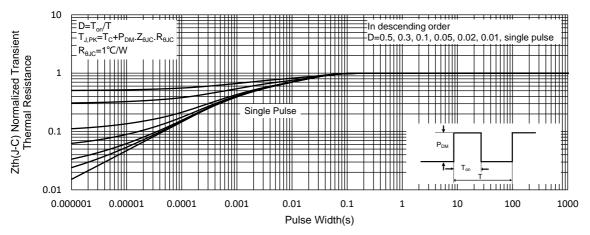


Fig.13 - Normalized Transient Thermal Impedance





Ordering Information

Device	Packing	
Part Number-TP	Tape&Reel: 800pcs/Reel	

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